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SI3948DV Rev.A

Symbol	Parameter	Conditions	Min	Тур	Max	Units
OFF CHAR	ACTERISTICS				-	
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = 250 \mu A$	30			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm D}$ = 250 µA, Referenced to 25 °C		23.6		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA
		$T_J = 55 \ ^{\circ}C$			10	μA
IGSSF	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate - Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			-100	nA
ON CHARA	CTERISTICS (Note 2)		•	•		
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1	1.8	3	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold VoltageTemp.Coefficient	$I_{\rm D}$ = 250 µA, Referenced to 25 °C		-4		mV/°C
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, \ \text{I}_{D} = 2.5 \text{ A}$		0.082	0.095	Ω
		T _J = 125 °C	;	0.122	0.152	
		$V_{GS} = 4.5 \text{ V}, I_{D} = 2.0 \text{ A}$		0.113	0.145	1
I _{D(on)}	On-State Drain Current	$V_{GS} = 10 \text{ V}, \text{ V}_{DS} = 5 \text{ V}$	10			А
9 _{FS}	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 2.5 A$		5		S
DYNAMIC C	HARACTERISTICS					
C _{iss}	Input Capacitance	$V_{DS} = 15 V, V_{GS} = 0 V,$		220		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		50		pF
C _{rss}	Reverse Transfer Capacitance			25		pF
SWITCHING	CHARACTERISTICS (Note 2)			-		
t _{D(on)}	Turn - On Delay Time	$V_{DD} = 5 V, I_{D} = 1 A,$		6	12	ns
ţ	Turn - On Rise Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		10	18	ns
t _{D(off)}	Turn - Off Delay Time			12	22	ns
ţ	Turn - Off Fall Time			2	6	ns
Q _g	Total Gate Charge	$V_{DS} = 15 \text{ V}, I_{D} = 2.5 \text{ A}$		2.3	3.2	nC
Q _{as}	Gate-Source Charge	$V_{GS} = 5 V$		0.7	1	nC
Q _{gd}	Gate-Drain Charge			0.9	1.3	nC
0	RCE DIODE CHARACTERISTICS		•	-	•	
I _s	Continuous Source Diode Current				0.75	Α
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 0.75 A$ (Note 2)		0.78	1.2	V

Notes:

1. R_{gut} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{gut} is guaranteed by design while $\mathsf{R}_{_{\theta}\mathsf{CA}}$ is determined by the user's board design.

2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%.

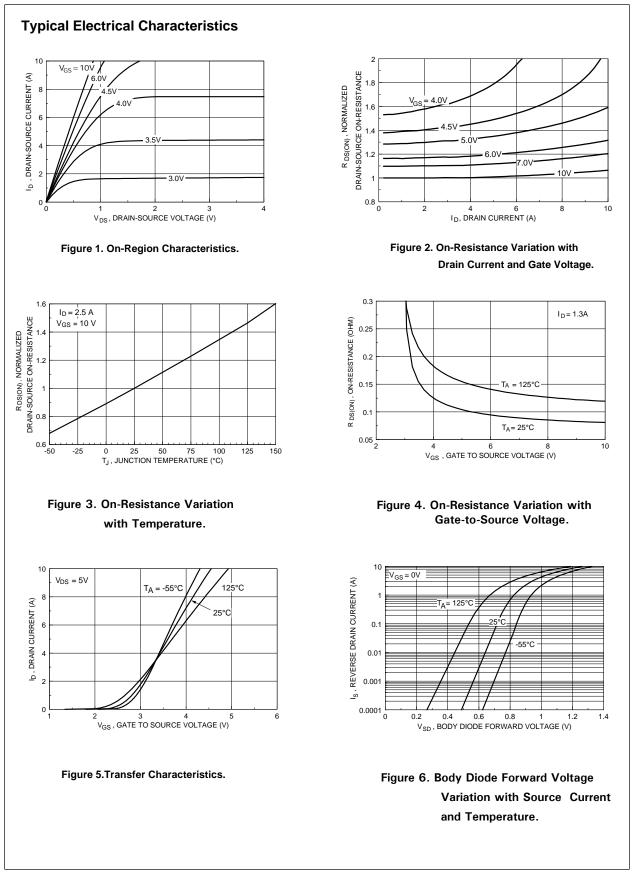


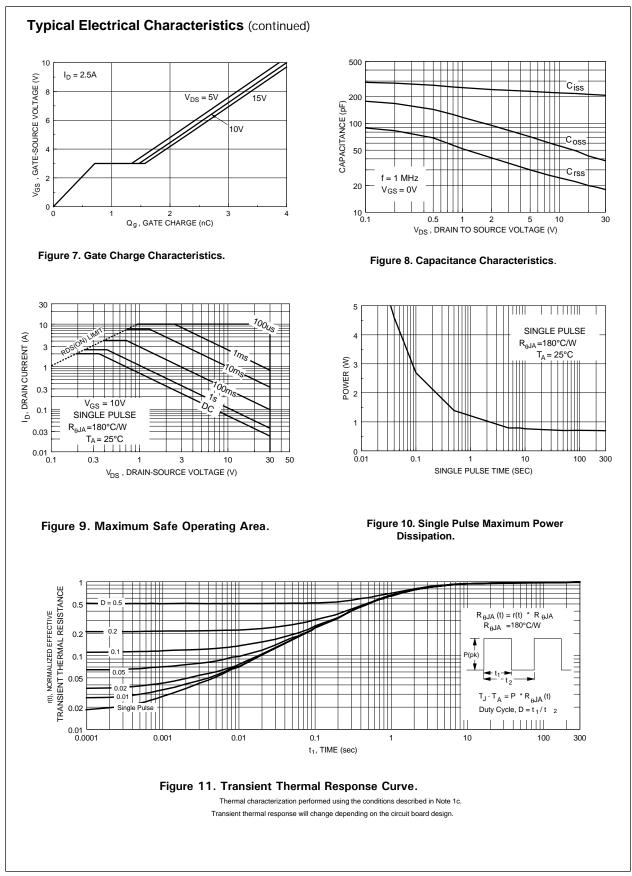
a. 130°C/W on a 0.125 in² pad of 2oz copper.



b. 140°C/W on a 0.005 in² pad of 2oz copper.

c. 180°C/W on a minimum pad.





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